# NSS20201MR6T1G

# 20 V, 3 A, Low V<sub>CE(sat)</sub> **NPN Transistor**

ON Semiconductor's e<sup>2</sup>PowerEdge family of low V<sub>CE(sat)</sub> transistors are miniature surface mount devices featuring ultra low saturation voltage (V<sub>CE(sat)</sub>) and high current gain capability. These are designed for use in low voltage, high speed switching applications where affordable efficient energy control is important.

Typical application are DC–DC converters and power management in portable and battery powered products such as cellular and cordless phones, PDAs, computers, printers, digital cameras and MP3 players. Other applications are low voltage motor controls in mass storage products such as disc drives and tape drives. In the automotive industry they can be used in air bag deployment and in the instrument cluster. The high current gain allows e<sup>2</sup>PowerEdge devices to be driven directly from PMU's control outputs, and the Linear Gain (Beta) makes them ideal components in analog amplifiers.

## **MAXIMUM RATINGS** ( $T_A = 25^{\circ}C$ )

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Rating	Symbol	Max	Unit
Collector-Emitter Voltage	V <sub>CEO</sub>	20	V
Collector-Base Voltage	V <sub>CBO</sub>	40	V
Emitter-Base Voltage	V <sub>EBO</sub>	5.0	V
Collector Current – Continuous	Ι <sub>C</sub>	2.0	A
Collector Current – Peak	I <sub>CM</sub>	3.0	А

## THERMAL CHARACTERISTICS

Characteristic	Symbol	Мах	Unit	
Total Device Dissipation $T_A = 25^{\circ}C$	P <sub>D</sub> (Note 1)	460	mW	
Derate above 25°C		3.7	mW/°C	
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$ (Note 1)	272	°C/W	
Total Device Dissipation $T_A = 25^{\circ}C$	P <sub>D</sub> (Note 2)	780	mW	
Derate above 25°C		6.3	mW/°C	
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$ (Note 2)	160	°C/W	
Thermal Resistance, Junction-to-Lead #1	$R_{\theta JL}$ (Note 1)	48 40	°C/W °C/W	
Junction-to-Lead #1	R <sub>0JL</sub> (Note 2)	40	-C/W	
Total Device Dissipation (Single Pulse < 10 s)	P <sub>Dsingle</sub> (Note 2)	1.5	W	
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	–55 to +150	°C	

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

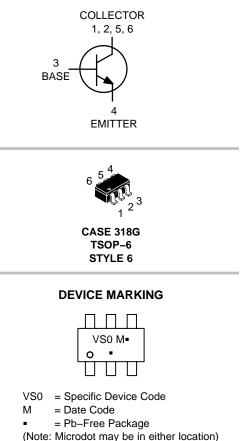
FR-4 @ 100 mm2, 2 oz copper traces.
FR-4 @ 500 mm2, 2 oz copper traces.



## **ON Semiconductor®**

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## 20 VOLTS **3.0 AMPS** $\begin{array}{l} \text{NPN LOW V}_{\text{CE(sat)}} \text{ TRANSISTOR} \\ \text{EQUIVALENT R}_{\text{DS(on)}} \text{ 100 m} \Omega \end{array}$



### ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
NSS20201MR6T1G	TSOP-6 (Pb-Free)	3000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

## NSS20201MR6T1G

## **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS		-		-	
Collector – Emitter Breakdown Voltage $(I_C = 10 \text{ mA}, I_B = 0)$	V <sub>(BR)CEO</sub>	20	-	_	V
Collector-Base Breakdown Voltage $(I_C = 0.1 \text{ mA}, I_E = 0)$	V <sub>(BR)CBO</sub>	40	_	-	V
Emitter – Base Breakdown Voltage $(I_E = 0.1 \text{ mA}, I_C = 0)$	V <sub>(BR)EBO</sub>	5.0	_	_	V
Collector Cutoff Current ( $V_{CB} = 40 \text{ V}, I_E = 0$ )	I <sub>CBO</sub>	-	_	0.1	μΑ
Collector–Emitter Cutoff Current (V <sub>CES</sub> = 20 V)	ICES	_	_	0.1	μΑ
Emitter Cutoff Current (V <sub>EB</sub> = 5.0 V)	I <sub>EBO</sub>	_		0.1	μΑ
ON CHARACTERISTICS		-		-	
DC Current Gain (Note 3) ( $I_C = 1.0 \text{ mA}, V_{CE} = 5.0 \text{ V}$ ) ( $I_C = 0.5 \text{ A}, V_{CE} = 5.0 \text{ V}$ ) ( $I_C = 1.0 \text{ A}, V_{CE} = 5.0 \text{ V}$ )	h <sub>FE</sub>	300 300 200	- - -	- - -	
	V <sub>CE(sat)</sub>	- - -		0.150 0.100 0.025	V
Base – Emitter Saturation Voltage (Note 3) $(I_C = 1.0 \text{ A}, I_B = 0.1 \text{ A})$	V <sub>BE(sat)</sub>	-	-	0.95	V
Base – Emitter Turn–on Voltage (Note 3) $(I_C = 1.0 \text{ A}, V_{CE} = 2.0 \text{ V})$	V <sub>BE(on)</sub>	-	-	0.90	V
Cutoff Frequency ( $I_C = 100 \text{ mA}, V_{CE} = 5.0 \text{ V}, f = 100 \text{ MHz}$	f <sub>T</sub>	200	-	_	MHz
Output Capacitance (f = 1.0 MHz)	C <sub>obo</sub>	_	_	15	pF

3. Pulsed Condition: Pulse Width  $\leq$  300 µsec, Duty Cycle  $\leq$  2%.





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